

30V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 30V
- Max Continuous Current I_C = 1A
- Low Saturation Voltage
- Complementary PNP Type: FZT589
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

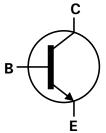
Mechanical Data

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)

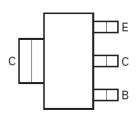




Top View



Device Symbol



Top View Pin-Out

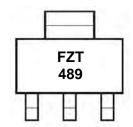
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT489TA	AEC-Q101	FZT489	7	12	1,000
FZT489QTA	Automotive	FZT489	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com

Marking Information



FZT489 = Product Type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	1	Α
Base Current	I _B	200	mA
Peak Pulse Current	I _{CM}	4	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Dissipation	(Note 6)	Б	2	W
Power Dissipation	(Note 7)	P _D	3	W
Thermal Resistance, Junction to Ambient	(Note 6)	В	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	− R _{θJA} −	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 8	R _{0JL}	19.41	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

- 6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.

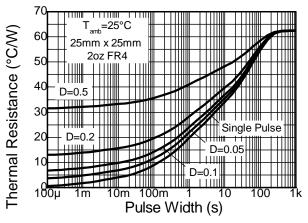
 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.

 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

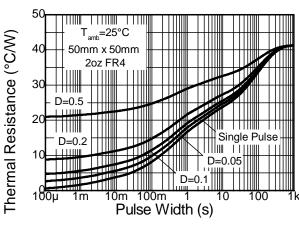
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



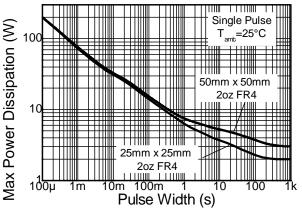
Thermal Characteristics and Derating Characteristics



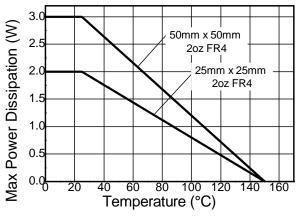
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve





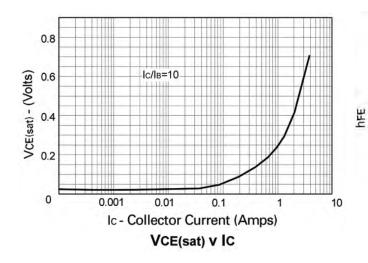
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

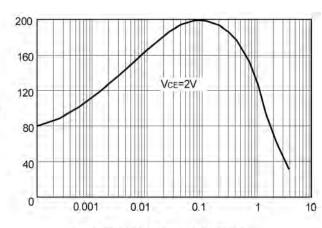
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	30	-	-	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	_	_	100	nA	V _{CB} = 30V
Collector Cut-off Current	Ices	=	=	100	nA	V _{CE} = 30V
Emitter Cut-off Current	I _{EBO}	_	_	100	nA	V _{EB} = 4V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	=	_	0.3	V	I _C = 1A, I _B = 100mA
Consider Entities Catalianess Foliage (Frete 19)	V CE(Sai)	_	_	0.6		$I_C = 2A$, $I_B = 200mA$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	-	_	1.1	V	$I_C = 1A$, $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 10)	$V_{BE(on)}$	_	=	1.0	V	$I_C = 1A$, $V_{CE} = 2V$
	h _{FE}	100	_	-	_	$I_C = 1 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Gain (Note 10)		100	_	300		$I_C = 1A$, $V_{CE} = 2V$
Do Garretti Gairi (Note 10)	··re	60	_	_		$I_C = 2A$, $V_{CE} = 2V$
		20	-	-		$I_C = 4A$, $V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 10)	f _T	150	-	_	MHz	V _{CE} = 10V, I _C = 50mA f = 100MHz
Output Capacitance (Note 10)	C_{obo}	_	_	10	pF	V _{CB} = 10V, f = 1MHz

Notes: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%

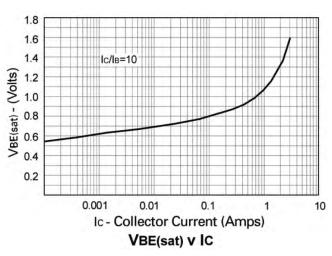


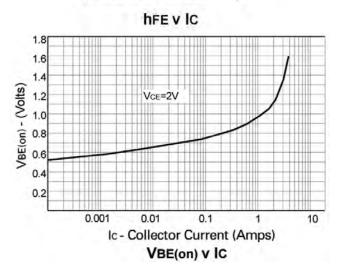
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

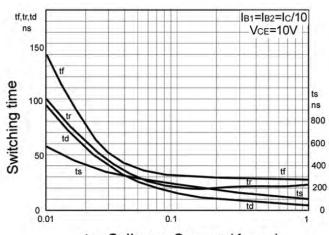




Ic - Collector Current (Amps)





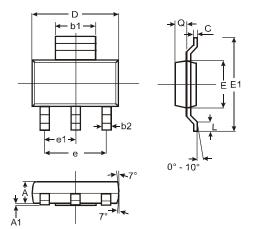


Ic - Collector Current (Amps)
Switching Speeds



Package Outline Dimensions

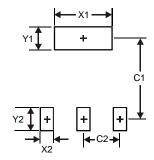
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3





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